RT1N137L

TRANSISTOR WITH RESISTOR FOR SWITCHING APPLICATION SILICON NPN EPITAXIAL TYPE

DESCRIPTION

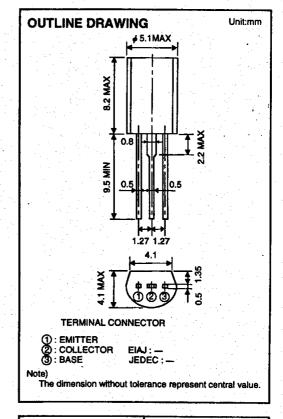
RT1N137L is a one chip transistor with built-in bias resistor, PNP type is RT1P137L.

FEATURE

- ●Built-in bias resistor (R₁=1kΩ,R₂=22kΩ)
- ●High collector current | IC=1A
- ●Low VCE(sat) VCE(sat)=0.3Vmax (@IC=300mA,IB=3mA)
- ●High collector dissipation Pc=900mW

APPLICATION

inverted circuit, switching circuit, interface circuit, driver circuit.



EQUIVALENT CIRCUIT BO R1 (OUT) R2 (GND) E C B

MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Ratings	Unit	
Vcво	Collector to Base voltage	40	V	
VEBO	Emitter to Base voltage	6	V	
VCEO	Collector to Emitter voltage	40	V	
lc	Collector current	1	A	
Ісм	Peak Collector current	2	· A	
Pc	Collector dissipation(Ta=25°C)	900	mW	
Tj	Junction temperature	+150	C	
Tstg	Storage temperature	-55 to +150	c	

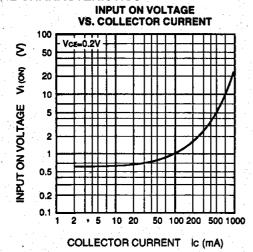
ELECTRICAL CHARACTERISTICS (Ta=25°C)

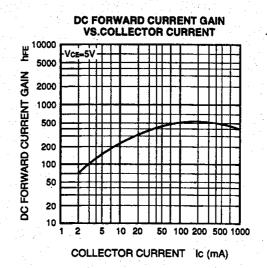
Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	O III
V(BR)CEO	C to E break down voltage	Ic=1mA,Ree=∞	40			V
Ісво	Collector cut off current	Vcb=40V,le=0			0.1	μΑ
hfe	DC forward current gain	Vce=5V,lc=100mA	100			
VCE(sat)	C to E saturation voltage	Ic=300mA,IB=3mA		0.1	0.3	V
VI(ON)	Input on voltage	Vce=0.2V,lc=300mA		2.3	4.0	v
VI(OFF)	Input off voltage	VcE=5V,lc=100 μA	0.4	0.5		V
R ₁	Input resistor		0.7	1.0	1.3	kΩ
R2/R1	Resistor ratio		20	22	24	
fr	Gain band width product	VcE=6V.IE=-10mA		150		MHz

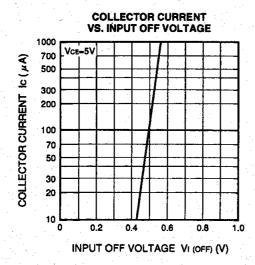
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TYPICAL CHARACTERISTICS







nunu Data Chaat III aan



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